

# 2SD1256

## Silicon NPN epitaxial planar type

For power switching

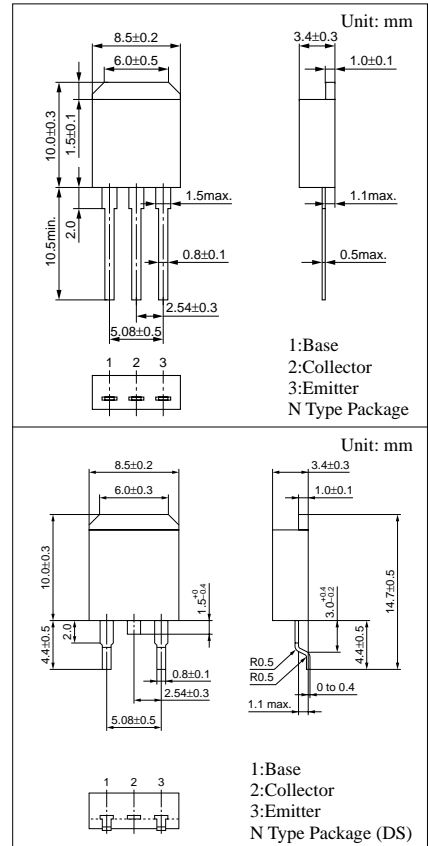
Complementary to 2SB933

### Features

- Low collector to emitter saturation voltage  $V_{CE(sat)}$
- Satisfactory linearity of forward current transfer ratio  $h_{FE}$
- Large collector current  $I_C$
- N type package enabling direct soldering of the radiating fin to the printed circuit board, etc. of small electronic equipment.

### Absolute Maximum Ratings ( $T_C=25^\circ\text{C}$ )

Parameter	Symbol	Ratings	Unit
Collector to base voltage	$V_{CBO}$	130	V
Collector to emitter voltage	$V_{CEO}$	80	V
Emitter to base voltage	$V_{EBO}$	7	V
Peak collector current	$I_{CP}$	10	A
Collector current	$I_C$	5	A
Collector power dissipation	$P_C$	$T_C=25^\circ\text{C}$	40
		$T_a=25^\circ\text{C}$	1.3
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$



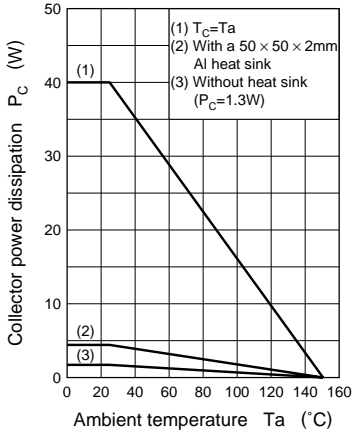
### Electrical Characteristics ( $T_C=25^\circ\text{C}$ )

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	$I_{CBO}$	$V_{CB} = 100V, I_E = 0$			10	$\mu\text{A}$
Emitter cutoff current	$I_{EBO}$	$V_{EB} = 5V, I_C = 0$			50	$\mu\text{A}$
Collector to emitter voltage	$V_{CEO}$	$I_C = 10\text{mA}, I_B = 0$	80			V
Forward current transfer ratio	$h_{FE1}$	$V_{CE} = 2V, I_C = 0.1A$	45			
	$h_{FE2}^*$	$V_{CE} = 2V, I_C = 2A$	60		260	
Collector to emitter saturation voltage	$V_{CE(sat)}$	$I_C = 4A, I_B = 0.2A$			0.5	V
Base to emitter saturation voltage	$V_{BE(sat)}$	$I_C = 4A, I_B = 0.2A$			1.5	V
Transition frequency	$f_T$	$V_{CE} = 10V, I_C = 0.5A, f = 10\text{MHz}$		30		MHz
Turn-on time	$t_{on}$	$I_C = 2A, I_{B1} = 0.2A, I_{B2} = -0.2A, V_{CC} = 50V$		0.5		$\mu\text{s}$
Storage time	$t_{stg}$			1.5		$\mu\text{s}$
Fall time	$t_f$			0.15		$\mu\text{s}$

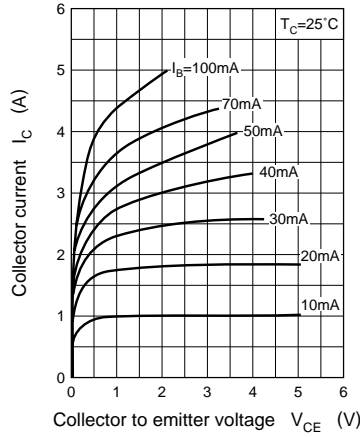
\* $h_{FE2}$  Rank classification

Rank	R	Q	P
$h_{FE2}$	60 to 120	90 to 180	130 to 260

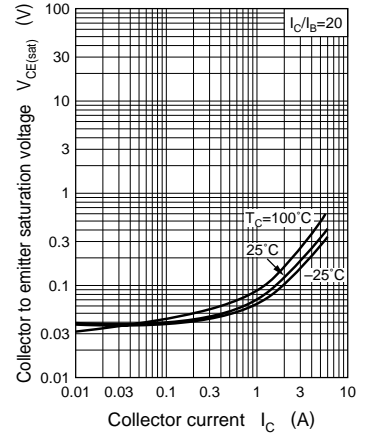
$P_C - T_a$



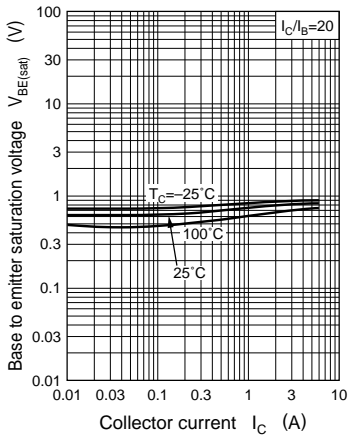
$I_C - V_{CE}$



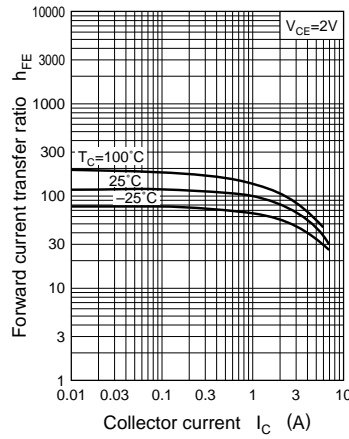
$V_{CE(sat)} - I_C$



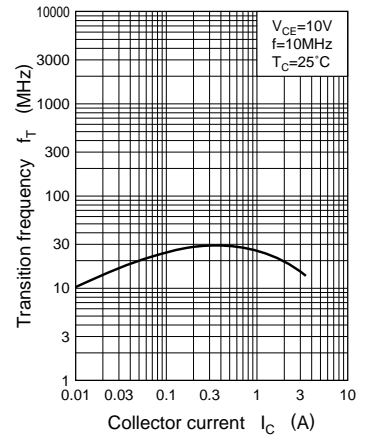
$V_{BE(sat)} - I_C$



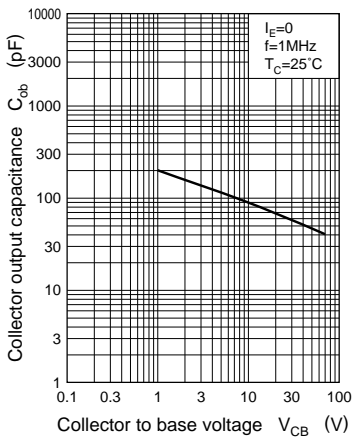
$h_{FE} - I_C$



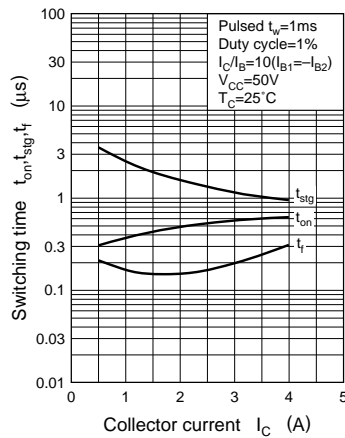
$f_T - I_C$



$C_{ob} - V_{CB}$



$t_{on}, t_{stg}, t_f - I_C$



Area of safe operation (ASO)

